Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1		("6337272").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/22 17:02
S2	2	("6458711").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/22 17:03
S3	2	("6725119").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/22 17:03
S4	2395	(clean\$4) and transistor and source and drain and gate and (heat\$4) and temperature and silicide and anneal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/23 15:17
S5		S4 and ((standard adj cleaning) or SC1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/23 15:17
S6	5	("5780361"   "5877085"   "5899720"   "5970370"   "6074960").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/23 16:32
S7	397	S4 and ((cobalt adj silicide) or CoSi)	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/23 16:33
S8	2284	(438/586).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/24 19:55
S9	11	S8 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/24 20:20

S10	3	S9 and power	US-PGPUB;	OR	ON	2006/05/24 20:23
			USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB			
S11	784	(438/597).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/24 20:23
S12		S11 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/24 20:36
S13	231	(438/630).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/24 20:36
S14	8	S13 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 11:46
S15	. 512	(438/649).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 11:46
S16	30	S15 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:08
S17	1769	(438/655).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:09

S18	51	S17 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:21
S19	327	(438/658).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:22
S20	5	S19 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:25
S21	787	(438/660).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:25
S22	13	S21 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:28
S23	787	(438/660).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:29
S24	13	S23 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:30
S25	507	(438/664).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:30

S26	. 35	S25 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:56
S27	648	(438/682).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/26 12:56
S28	57	S27 and (sputter\$3 or PVD or (physical adj vapor adj deposit\$3)) and monosilicid\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/26 12:58

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